TOSHIBA Intelligent Power Module Silicon N Channel IGBT

MIG50J101H

High Power Switching Applications Motor Control Applications

- Integrates inverter & control circuits (IGBT drive units, protection units for over-current, under-voltage & over-temperature) in one package.
- The electrodes are isolated from case.

High speed type IGBT : $V_{CE (sat)} = 2.5 \text{ V (max)}$

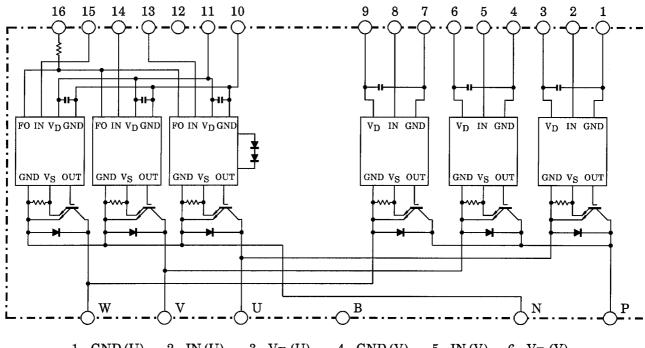
 $t_{off} = 3.0 \mu s (max)$

 $t_{rr} = 0.30 \ \mu s \ (max)$

Package dimensions : TOSHIBA 2-110A1A

Weight: 520 g

Equivalent Circuit



1. GND (U) 7. GND (W) 2. IN(U)

 $\begin{array}{ll} 3. & \mathbf{V_D}\left(\mathbf{U}\right) \\ 9. & \mathbf{V_D}\left(\mathbf{W}\right) \end{array}$

4. GND(V) 10.GND(L) 5. IN(V) $11.V_D(L)$ 6. $V_D(V)$ 12.0PEN

13.IN(X)

8. IN(W) 14.IN(Y)

15.IN(Z)

16.FO

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Maximum Ratings ($T_j = 25$ °C)

| Stage | Characteristic | Condition | Symbol | Ratings | Unit |
|----------|-----------------------------|------------------------------|------------------|------------|------|
| Inverter | Supply voltage | P-N power terminal | V _{CC} | 450 | V |
| | Collector-emitter voltage | _ | V _{CES} | 600 | V |
| | Collector current | Tc = 25°C, DC | IC | 50 | Α |
| | Forward current | Tc = 25°C, DC | IF | 50 | Α |
| | Collector power dissipation | Tc = 25°C | PC | 150 | W |
| | Junction temperature | _ | Tj | 150 | °C |
| Control | Control supply voltage | V _D -GND terminal | V _D | 20 | V |
| | Input voltage | IN-GND terminal | V _{IN} | 20 | V |
| | Fault output voltage | FO-GND (L) terminal | V _{FO} | 20 | V |
| | Fault output current | FO sink current | I _{FO} | 14 | mA |
| Module | Operating temperature | _ | TC | -20 ~ +100 | °C |
| | Storage temperature range | _ | T _{stg} | -40 ~ +125 | °C |
| | Isolation voltage | AC 1 minute | V _{ISO} | 2500 | V |
| | Screw torque | M5 | _ | 3 | Nm |

Electrical Characteristics ($T_j = 25$ °C)

a. Inverter Stage

| Characteristic | Symbol | Symbol Test Condition | | Min | Тур. | Max | Unit |
|---------------------------------------|-----------------------|---|------------------------|-----|------|-----|------|
| Collector cut-off current | lony | $V_{CE} = 600V$ $T_j = 25^{\circ}C$ $T_j = 125^{\circ}C$ | T _j = 25°C | _ | _ | 1 | - mA |
| Collector cut-on current | ICEX | | T _j = 125°C | _ | _ | 20 | |
| Collector-emitter saturation voltage | V05 (1) | 45 1/ 0 0 / 1 | T _j = 25°C | _ | 2.0 | 2.5 | V |
| Collector-entitler Saturation voltage | V _{CE} (sat) | | T _j = 125°C | _ | 2.0 | _ | |
| Forward voltage | V _F | I _F = 50A | | _ | 2.1 | 3.0 | V |
| | t _{on} | V - 200 V I - 50 A | | ı | 0.8 | 2.0 | |
| Switching time | t _{off} | $V_{CC} = 300 \text{ V, } I_{C} = 50 \text{ A}$ $V_{D} = 15 \text{ V, } V_{IN} = 15 \text{ V}$ | → 0 V | I | 1.2 | 3.0 | 110 |
| Switching time | t _f | Inductive load | (Note 1) | | 0.25 | 0.5 | μs |
| | t _{rr} | | (140te 1) | _ | 0.1 | 0.3 | |

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b. Control Stage $(T_j = 25^{\circ}C)$

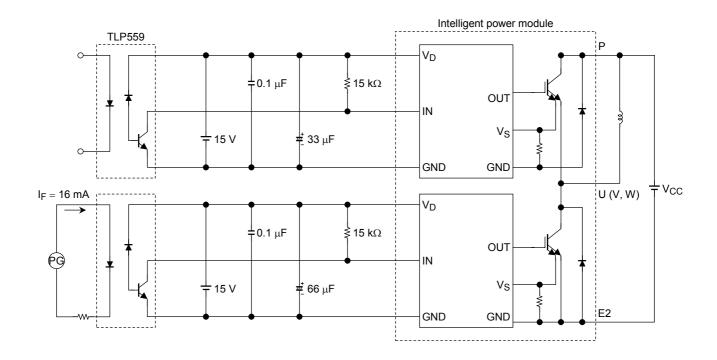
| Characteristic | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|-------------|-----------------------|---|------|------|------|------|
| Control circuit current | High side | I _{D (H)} | -V _D = 15 V | _ | 8 | _ | mA |
| | Low side | I _{D (L)} | | | 24 | _ | |
| Input-on signal voltage | | V _{IN (on)} | V _D = 15 V, I _C = 50 mA | 1.3 | 1.5 | 1.7 | V |
| Input-off signal voltage | | V _{IN (off)} | V _D = 15 V, I _C = 50 mA | 2.2 | 2.5 | 2.8 | V |
| Fault output current | Protection | I _{FO (on)} | _ | 8 | 10 | 12 | mA |
| | Normal | I _{FO (off)} | | _ | _ | 1 | |
| Over current protection trip level | Inverter | ОС | V _D = 15 V, T _j = 125°C | 75 | 100 | _ | А |
| Short circuit protection trip level | Inverter | ОС | V _D = 15 V, T _j = 125°C | 110 | 150 | _ | А |
| Over current cut-off time | | t _{off (OC)} | V _D = 15 V | _ | 5 | _ | μs |
| Over | Trip level | ОТ | Case temperature | 118 | 125 | °C | |
| temperature protection | Reset level | OTr | | _ | 98 | _ | |
| Control supply under voltage protection | Trip level | UV | | 11.0 | 12.0 | 12.5 | ., |
| | Reset level | UVr | _ | _ | 12.5 | _ | V |
| Fault output pulse width | | t _{FO} | V _D = 15 V | 1 | 2 | 3 | ms |

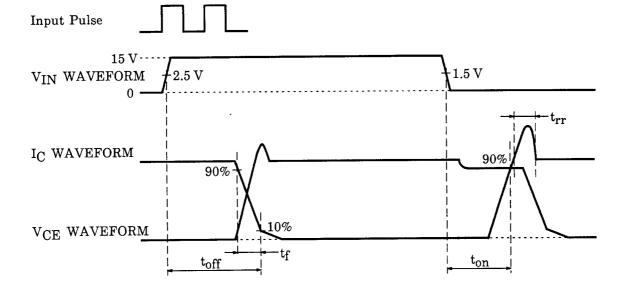
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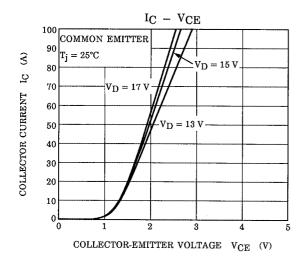
c. Thermal Resistance ($T_j = 25$ °C)

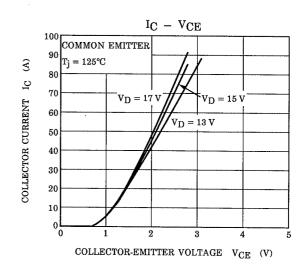
| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-------------------------------------|-----------------------|---------------------|-----|------|-------|--------|
| Junction to case thermal resistance | D., | Inverter IGBT stage | _ | _ | 0.833 | - °C/W |
| ounction to case thermal resistance | R _{th (j-c)} | Inverter FRD stage | - | 1 | 2.000 | |
| Case to fin thermal resistance | R _{th (c-f)} | Compound is applied | _ | 0.05 | _ | °C/W |

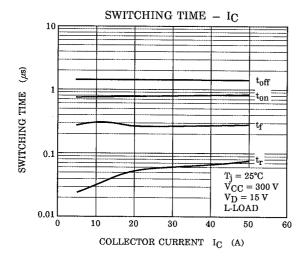
Note 1: Switching time test circuit & timing chart

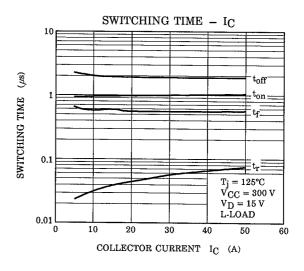


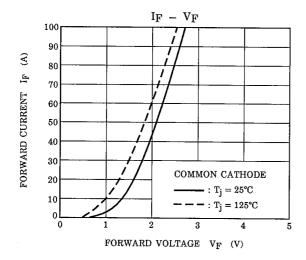


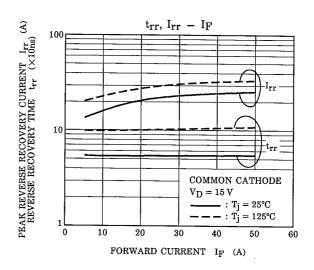




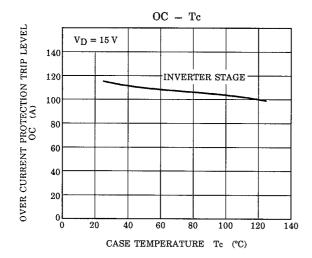


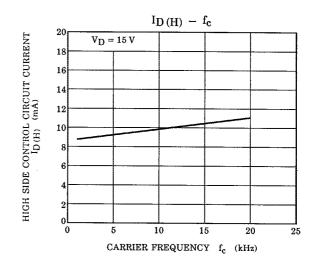


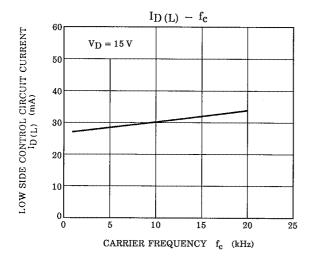


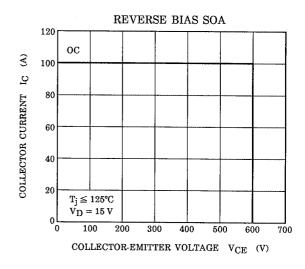


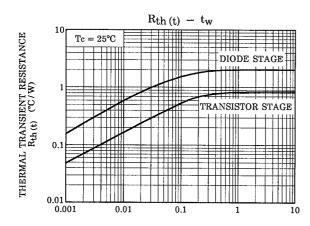
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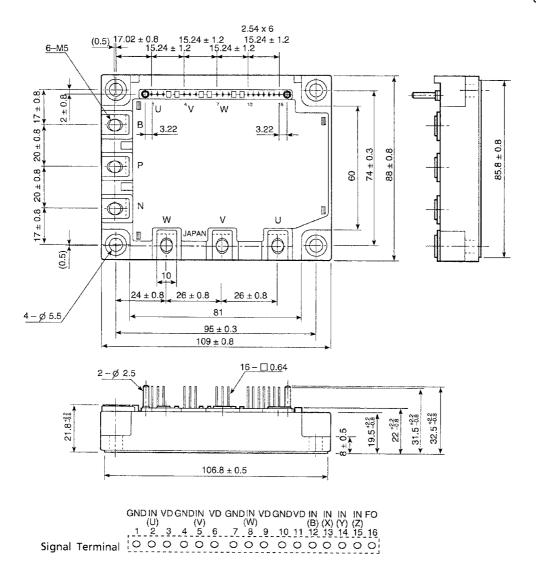






Package Dimensions: TOSHIBA 2-110A1A

Unit: mm



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